



ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18
Stylesheet Version v18.0

Title of Invention	High-Voltage Transistor With A Multi-Layer Conduction Region																																		
<p>Application Number: 09/961229 Confirmation Number: 4375 First Named Applicant: Vladimir Rumennik Attorney Docket Number: 03692.P007XD4 Art Unit: 2811 Examiner: Shouxiang Hu Search string: (6633065 or 6639277).pn.</p> <p style="text-align: right;">RECEIVED NOV 25 2003 TECHNOLOGY CENTER 2800</p>																																			
<h3>US Patent Documents</h3> <p>Note: Applicant is not required to submit a paper copy of cited US Patent Documents</p> <table border="1"><thead><tr><th>init</th><th>Cite.No.</th><th>Patent No.</th><th>Date</th><th>Patentee</th><th>Kind</th><th>Class</th><th>Subclass</th></tr></thead><tbody><tr><td></td><td>1</td><td>6633065</td><td>2003-10-14</td><td>Rumennik et al.</td><td>B2</td><td></td><td></td></tr><tr><td></td><td>2</td><td>6639277</td><td>2003-10-28</td><td>Rumennik et al.</td><td>B2</td><td></td><td></td></tr></tbody></table> <h3>Remarks</h3> <p>Note: Remarks are not for responding to an office action.</p> <p>This information disclosure statement is being submitted concurrent with the filing of a Request for Continued Examination in the above-referenced application.</p> <h3>Signature</h3> <table border="1"><tr><td>Examiner Name</td><td>Date</td></tr><tr><td></td><td></td></tr></table>								init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass		1	6633065	2003-10-14	Rumennik et al.	B2				2	6639277	2003-10-28	Rumennik et al.	B2			Examiner Name	Date		
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Electronic Filing System (EFS) Data

Electronic Patent Application Submission

USPTO Use Only

EFS ID: 50735
Application ID: 09961229
Title of Invention: High-Voltage Transistor With A Multi-Layer Conduction Region
First Named Inventor: Vladimir Rumennik
Domestic/Foreign Application: Domestic Application
Filing Date: 2001-09-20
Effective Receipt Date: 2003-11-17
Submission Type: Information Disclosure Statement
Filing Type:
Confirmation number: 4375
Attorney Docket Number: 03692.P007XD4



Total Fees Authorized:

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TRANSMITTAL

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Stylesheet Version v1.1.0

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Application Number: 09/961229 Date: 2001-09-20 First Named Applicant: Vladimir Rumennik Confirmation Number: 4375 Attorney Docket Number: 03692.P007XD4		RECEIVED TECHNOLOGY CENTER 2800 NOV 25 2003
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Bradley J Bereznak Registered Number: 33,474	BBB	Attorney
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Comments		